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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<a href="http://www.renesas.com">http://www.renesas.com</a>)

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# H5N5012P

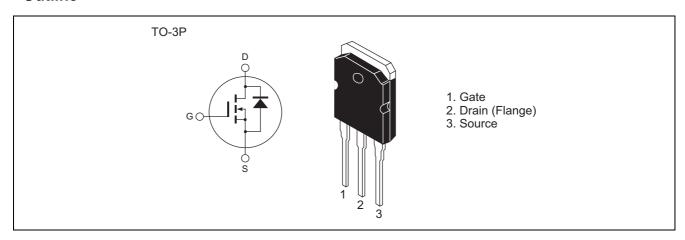
# Silicon N Channel MOS FET High Speed Power Switching

REJ03G0378-0200Z Rev.2.00 Jun.17.2004

#### **Features**

- Low on-resistance
- Low leakage current
- High speed switching
- Built-in fast recovery diode

#### **Outline**



### **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Drain to Source voltage	V <sub>DSS</sub>	500	V
Gate to Source voltage	V <sub>GSS</sub>	±30	V
Drain current	I <sub>D</sub>	25	А
Drain peak current	I <sub>D (pulse)</sub> Note1	100	А
Body-Drain diode reverse Drain current	I <sub>DR</sub>	25	А
Avalanche current	I <sub>AP</sub> Note3	7	А
Channel dissipation	Pch Note2	150	W
Channel to case thermal impedance	θch-c	0.833	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

- 2. Value at Tc = 25°C
- 3. STch =  $25^{\circ}$ C, Tch  $\leq 150^{\circ}$ C

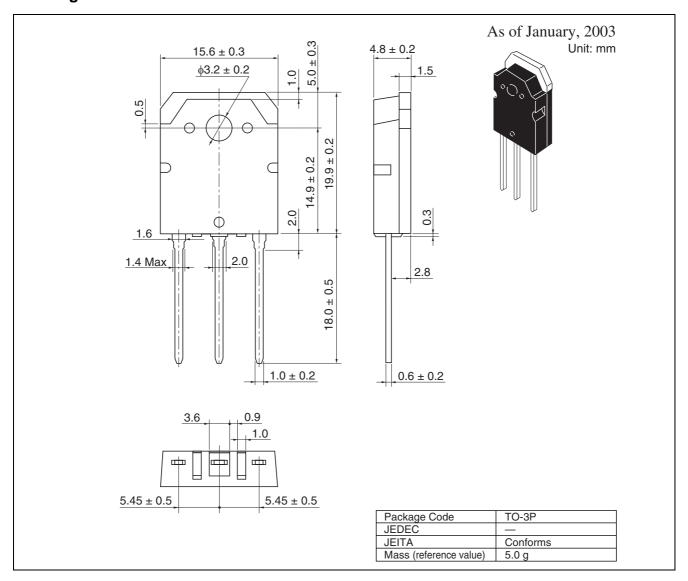
#### **Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Min	Тур	Max	Unit	Test conditions	
Drain to Source breakdown voltage	$V_{(BR)DSS}$	500	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$	
Zero Gate voltage drain current	I <sub>DSS</sub>	_	_	10	μΑ	$V_{DS} = 500 \text{ V}, V_{GS} = 0$	
Gate to Source leak current	I <sub>GSS</sub>	_	_	±0.1	μΑ	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$	
Gate to Source cutoff voltage	$V_{GS(off)}$	1.5	_	4.0	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$	
Forward transfer admittance	yfs	13	23	_	S	$I_D = 12.5 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note4}}$	
Static Drain to Source on state	R <sub>DS(on)</sub>	_	0.180	0.225	Ω	$I_D = 12.5 \text{ A}, V_{GS} = 10 \text{ V}^{Note4}$	
resistance							
Input capacitance	Ciss	_	3600	_	pF	V <sub>DS</sub> = 25 V	
Output capacitance	Coss	_	385	_	pF	$V_{GS} = 0$	
Reverse transfer capacitance	Crss	_	95	_	pF	f = 1 MHz	
Turn-on delay time	t <sub>d(on)</sub>	_	40	_	ns	I <sub>D</sub> = 12.5 A	
Rise time	t <sub>r</sub>	_	100	_	ns	V <sub>GS</sub> = 10 V	
Turn-off delay time	t <sub>d(off)</sub>	_	270	_	ns	$R_L = 20 \Omega$	
Fall time	t <sub>f</sub>	_	150	_	ns	$Rg = 10 \Omega$	
Total Gate charge	Qg	_	145	_	nC	V <sub>DD</sub> = 400 V	
Gate to Source charge	Qgs	_	20	_	nC	V <sub>GS</sub> = 10 V	
Gate to Drain charge	Qgd	_	70	_	nC	I <sub>D</sub> = 25 A	
Body-Drain diode forward voltage	$V_{DF}$	_	1.0	1.5	V	$I_F = 25 \text{ A}, V_{GS} = 0^{\text{Note4}}$	
Body-Drain diode reverse recovery time	trr	_	170	_	ns	I <sub>F</sub> = 25 A, V <sub>GS</sub> = 0	
Body-Drain diode reverse recovery	Qrr	_	1.0	_	μС	diF/dt = 100 A/μs	
charge							

Notes: 4. Pulse test

#### **Package Dimensions**



## **Ordering Information**

Part Name	Quantity	Shipping Container
H5N5012P-E	30 pcs	Plastic magazine

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